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### FDS86106 N-Channel Power Trench<sup>®</sup> MOSFET 100 V, 3.4 A, 105 m $\Omega$

#### Features

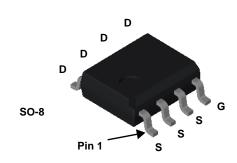
- Max  $r_{DS(on)}$  = 105 m $\Omega$  at V<sub>GS</sub> = 10 V, I<sub>D</sub> = 3.4 A
- Max  $r_{DS(on)}$  = 171 m $\Omega$  at V<sub>GS</sub> = 6 V, I<sub>D</sub> = 2.7 A
- High performance trench technology for extremely low r<sub>DS(on)</sub>
- High power and current handling capability in a widely used surface mount package
- 100% UIL Tested
- RoHS Compliant

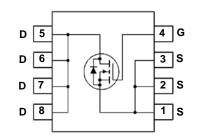


This N-Channel MOSFET is produced using Fairchild Semiconductor's advanced Power Trench<sup>®</sup> process that has been optimized for  $r_{DS(on)}$ , switching performance and ruggedness.

### Applications

- Synchronous Rectifier
- Primary Switch For Bridge Topology





### **MOSFET Maximum Ratings** $T_A = 25 \degree C$ unless otherwise noted

Symbol	Parameter			Ratings	Units
V <sub>DS</sub>	Drain to Source Voltage			100	V
V <sub>GS</sub>	Gate to Source Voltage			±20	V
	Drain Current -Continuous			3.4	^
D	-Pulsed			15	A
E <sub>AS</sub>	Single Pulse Avalanche Energy		(Note 3)	13	mJ
D	Power Dissipation	Г <sub>А</sub> = 25 °С	(Note 1a)	5.0	W
PD	Power Dissipation T	A = 25 °C	(Note 1b)	2.5	vv
T <sub>J</sub> , T <sub>STG</sub>	Operating and Storage Junction Temperature Range	е		-55 to +150	°C

#### **Thermal Characteristics**

$R_{\thetaJC}$	Thermal Resistance, Junction to Case	(Note 1)	2.5	°C/W
$R_{\thetaJA}$	Thermal Resistance, Junction to Ambient	(Note 1a)	50	0/00

### **Package Marking and Ordering Information**

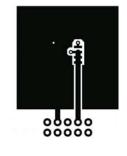
Device Marking	Device	Package	Reel Size	Tape Width	Quantity
FDS86106	FDS86106	SO-8	13 "	12 mm	2500 units

July 2011

Symbol	Parameter	Test Conditions	Min	Тур	Max	Units	
Off Chara	octeristics						
BV <sub>DSS</sub>	Drain to Source Breakdown Voltage	$I_{D} = 250 \ \mu A, \ V_{GS} = 0 \ V$	100		1	V	
$\frac{\Delta BV_{DSS}}{\Delta T_J}$	Breakdown Voltage Temperature Coefficient	$I_D = 250 \ \mu$ A, referenced to 25 °C		67		mV/°C	
I <sub>DSS</sub>	Zero Gate Voltage Drain Current	V <sub>DS</sub> = 80 V, V <sub>GS</sub> = 0 V			1	μΑ	
I <sub>GSS</sub>	Gate to Source Leakage Current	$V_{GS} = \pm 20 \text{ V}, V_{DS} = 0 \text{ V}$			±100	nA	
On Chara	cteristics						
V <sub>GS(th)</sub>	Gate to Source Threshold Voltage	$V_{GS} = V_{DS}, I_{D} = 250 \ \mu A$	2	2.9	4	V	
$\frac{\Delta V_{GS(th)}}{\Delta T_J}$	Gate to Source Threshold Voltage Temperature Coefficient	$I_D = 250 \ \mu\text{A}$ , referenced to 25 °C		-9		mV/°C	
j	Static Drain to Source On Resistance	V <sub>GS</sub> = 10 V, I <sub>D</sub> = 3.4 A		83	105		
r <sub>DS(on)</sub>		$V_{GS} = 6 V, I_D = 2.7 A$		115	171	mΩ	
20(01)		$V_{GS} = 10 \text{ V}, \text{ I}_{D} = 3.4 \text{ A}, \text{ T}_{J} = 125 \text{ °C}$		143	177	-	
9 <sub>FS</sub>	Forward Transconductance	$V_{\rm DS} = 10$ V, $I_{\rm D} = 3.4$ A		6		S	
C <sub>iss</sub> C <sub>oss</sub> C <sub>rss</sub>	Input Capacitance Output Capacitance Reverse Transfer Capacitance	$V_{DS} = 50 \text{ V}, V_{GS} = 0 \text{ V},$ f = 1 MHz		156 47 2	208 62 3	pF pF pF	
C <sub>oss</sub>					-		
R <sub>q</sub>	Gate Resistance			0.9	-	Ω	
0	g Characteristics						
t <sub>d(on)</sub>	Turn-On Delay Time			5	10	ns	
t <sub>r</sub>	Rise Time	V <sub>DD</sub> = 50 V, I <sub>D</sub> = 3.4 A,		2	10	ns	
t <sub>d(off)</sub>	Turn-Off Delay Time	$V_{GS}$ = 10 V, $R_{GEN}$ = 6 $\Omega$		8	15	ns	
t <sub>f</sub>	Fall Time			2	10	ns	
Q <sub>g(TOT)</sub>	Total Gate Charge	$V_{GS} = 0 V$ to 10 V		3	4	nC	
<b>⊲</b> g(101)	Total Gate Charge	$V_{GS} = 0 V \text{ to } 5 V V_{DD} = 50 V$		1.6	2.3	nC	
Q <sub>gs</sub>	Total Gate Charge	I <sub>D</sub> = 3.4 A		0.8		nC	
Q <sub>gd</sub>	Gate to Drain "Miller" Charge			0.8		nC	
Drain-Sou	urce Diode Characteristics						
V	Source to Drain Diode, Eenward Valtage	$V_{GS} = 0 V, I_S = 3.4 A$ (Note 2)		0.86	1.3	V	
V <sub>SD</sub>	Source to Drain Diode Forward Voltage	$V_{GS} = 0 V, I_S = 2.1 A$ (Note 2)		0.83	1.2	v	
t	Reverse Recovery Time			34	54	ns	
t <sub>rr</sub>		— I <sub>F</sub> = 3.4 A, di/dt = 100 A/μs					

NOTES:

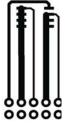
1. R<sub>0,A</sub> is determined with the device mounted on a 1 in<sup>2</sup> pad 2 oz copper pad on a 1.5 x 1.5 in. board of FR-4 material. R<sub>0,JC</sub> is guaranteed by design while R<sub>0CA</sub> is determined by the user's board design.



2. Pulse Test: Pulse Width < 300  $\mu s,$  Duty cycle < 2.0 %.

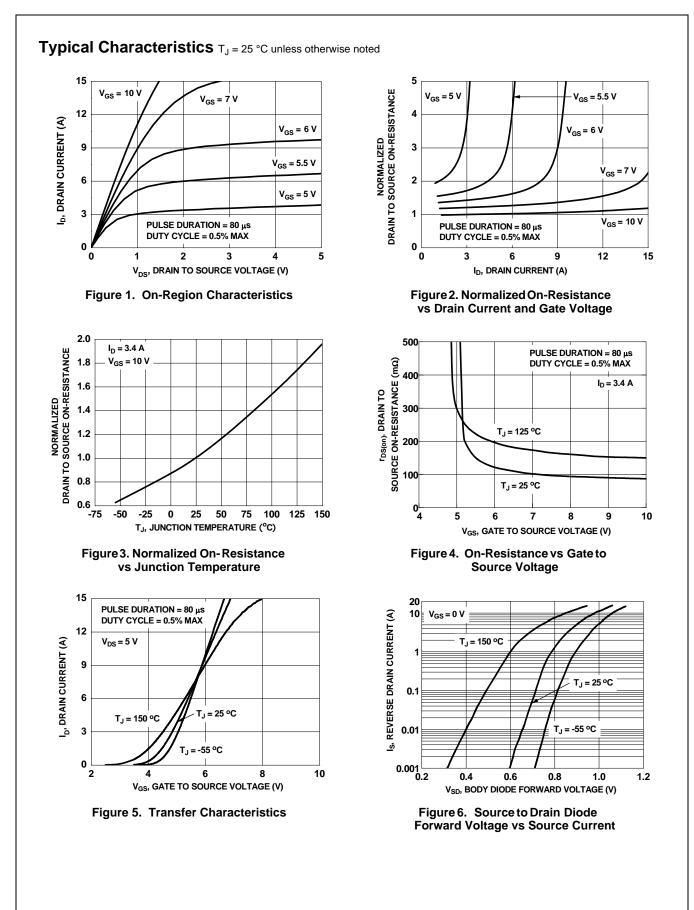
3. Starting  $T_J$  = 25  $^oC;$  N-ch: L = 3 mH,  $I_{AS}$  = 3 A,  $V_{DD}$  = 100 V,  $V_{GS}$  = 10 V.

a) 50 °C/W when mounted on a 1 in<sup>2</sup> pad of 2 oz copper.



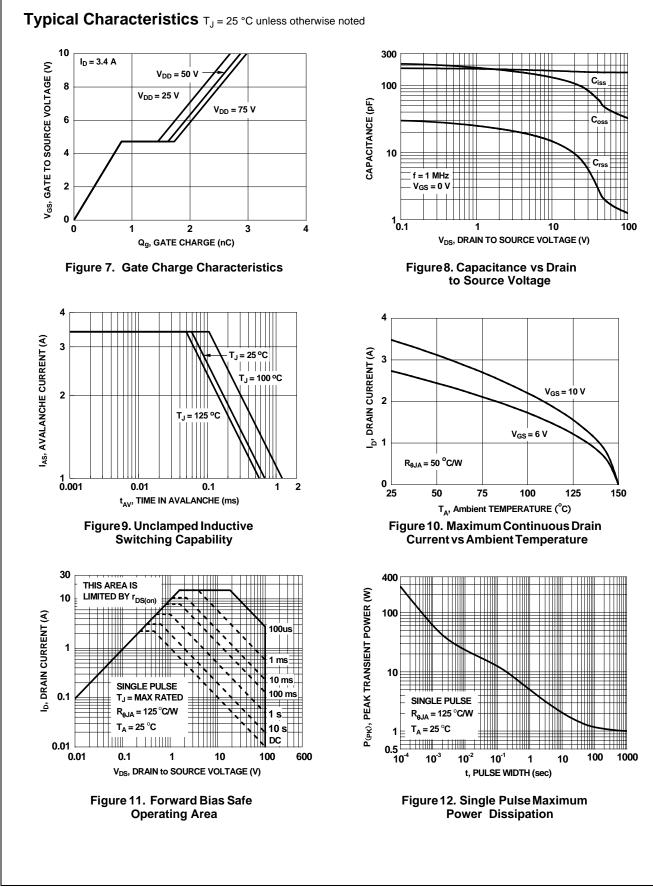
b) 125 °C/W when mounted on a minimum pad.

FDS86106 N-Channel Power Trench<sup>®</sup> MOSFET

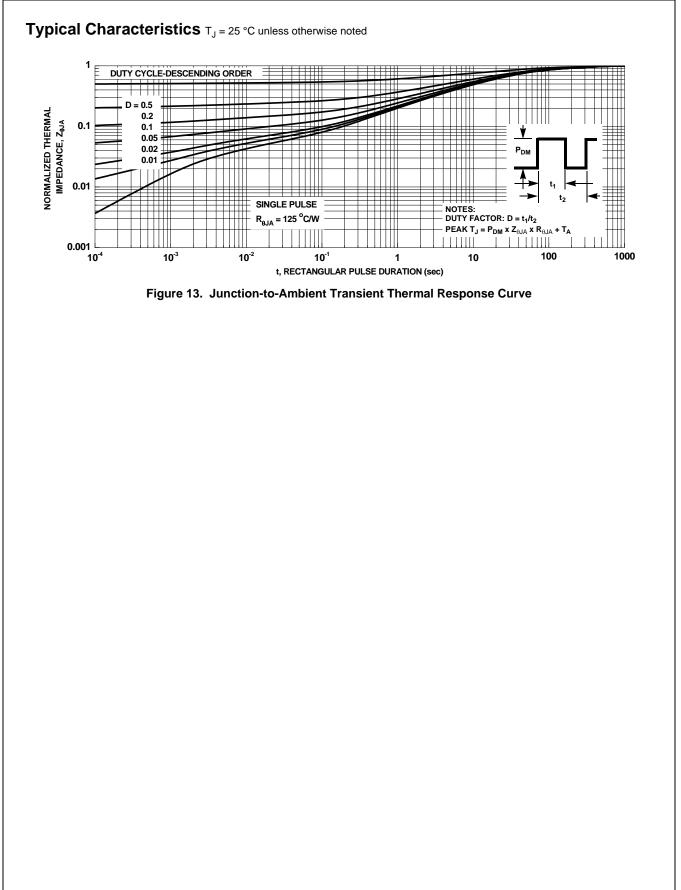


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